## SFF10A05CTG-SFF10A60CTG SUPERFAST RECOVERY RECTIFIERS

#### **FEATURES**

- Plastic package has Underwriters Laboratory Flammability Classification 94V-O.
  Flame Retardant Epoxy Molding Compound.
- Exceeds environmental standards of MIL-S-19500/228
- · Low power loss, high efficiency.
- · Low forwrd voltge, high current capability
- · High surge capacity.
- · Super fast recovery times, high voltage.
- · In compliance with EU RoHS 2002/95/EC directives

#### **MECHANICAL DATA**

· Case: ITO-220F Molded plastic

• Terminals: Lead solderable per MIL-STD-750, Method 2026

Polarity: As marked.Standard packaging: Any

· Weight: 0.0655 ounces, 1.859grams.



TO-220F

## MAXIMUM RATING AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%

PARAMETER	SYMBOL	SFF10A05 CTG	SFF10A10 CTG	SFF10A10A CTG	SFF10A20 CTG	SFF10A30 CTG	SFF10A40 CTG	SFF10A60 CTG	UNITS
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	50	100	150	200	300	400	600	V
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	105	140	210	280	420	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	150	200	300	400	600	V
Maximum Average Forward Current at Tc =100°C	I <sub>F(AV)</sub>	10.0						А	
Peak Forward Surge Current, 8.3ms single half sine-wave superimposed on rated load(JEDEC method)	I <sub>FSM</sub>	150							Α
Maximum Forward Voltage at 5A, per element	V <sub>F</sub>	0.95				1.30		1.7	V
Maximum DC Reverse Current at T <sub>J</sub> =25°C Rated DC Blocking VoltageT <sub>J</sub> =100°C	I <sub>R</sub>	1.0 500							
Maximum Reverse Recovery Time (Note 2)	t <sub>rr</sub>				35				ns
Typical Junction capacitance (Note 1)	C¹				62				pF
Typical Thermal Resistance	R <sub>eJC</sub>				3.0			, C	°C /
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 to +150							°C

### NOTES:

- 1. Measured at 1 MHz and applied reverse voltage of 4.0 VDC.
- 2. Reverse Recovery Test Conditions: I<sub>F</sub>=.5A, I<sub>R</sub>=1A, Irr=.25A
- 3. Both Bonding and Chip structure are available.



# **RATING AND CHARACTERISTIC CURVES**

Fig. 1-FORWARD CURRENT DERATING CURVE

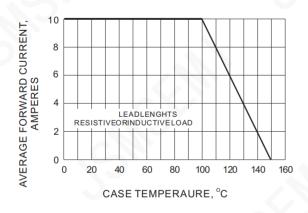


Fig.2-MAXIMUM NON-REPETITIVE SURGE CURRENT

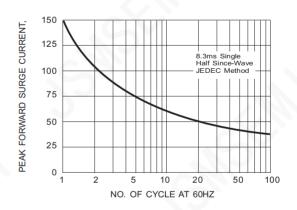


Fig.3-TYPICAL REVERSE CHARACTERISTIC

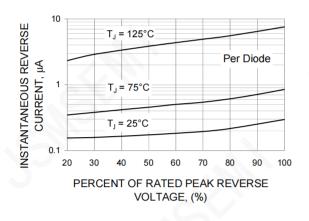


Fig.4-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTIC

